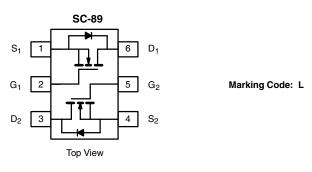


Vishay Siliconix

N-Channel 20 V (D-S) MOSFET

PRODUCT SI	JMMARY	
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (mA)
20	5 at V _{GS} = 4.5 V	200
	7 at V _{GS} = 2.5 V	175
	9 at V _{GS} = 1.8 V	150
	10 at V _{GS} = 1.5 V	50



Ordering Information: Si1034X-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFET: 1.5 V Rated
- Low-Side Switching
- Low On-Resistance: 5 Ω
- Low Threshold: 0.9 V (typ.)
- Fast Switching Speed: 35 ns (typ.)
- 1.5 V Operation
- Gate-Source ESD Protected: 2000 V
- Compliant to RoHS Directive 2002/95/EC

BENEFITS

- Ease in Driving Switches
- Low Offset (Error) Voltage
- Low-Voltage Operation
- High-Speed Circuits
- Low Battery Voltage Operation

APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories
- Battery Operated Systems
- Power Supply Converter Circuits
- Load/Power Switching Cell Phones, Pagers

ABSOLUTE MAXIMUM RATINGS	$(T_A = 25 \ ^{\circ}C, unle$	ss otherwise r	noted)			
Parameter		Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	20		V	
Gate-Source Voltage		V _{GS}	± 5			
	T _A = 25 °C	- I _D	190	180		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C		140	130		
Pulsed Drain Current ^b		I _{DM}	650		mA	
Continuous Source Current (Diode Conduction)		۱ _S	450	380		
Maximum Power Dissipation ^a	T _A = 25 °C	P _D	280	250	mW	
	T _A = 85 °C		145	130		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	
Gate-Source ESD Rating (HBM, Method 3015)		ESD	2000		V	

Notes:

a. Surface mounted on FR4 board.

b. Pulse width limited by maximum junction temperature.



FREE

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SPECIFICATIONS (T _A =	25 °C, unl	ess otherwise noted)					
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	0.40		1.2	V	
Cata Bady Laskaga	1	$V_{DS} = 0 V, V_{GS} = \pm 2.8 V$		± 0.5	± 1.0		
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 4.5 V		± 1.0	± 3.0	μΑ	
Zara Cata Valtaga Drain Compart		$V_{DS} = 16 V, V_{GS} = 0 V$		1	500	nA	
Zero Gate Voltage Drain Current	IDSS	V_{DS} = 16 V, V_{GS} = 0 V, T_{J} = 85 °C			10	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 4.5 V$	250			mA	
Drain-Source On-State		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 200 \text{ mA}$			5	Ω	
	R _{DS(on)}	V _{GS} = 2.5 V, I _D = 175 mA			7		
Resistance ^a		V _{GS} = 1.8 V, I _D = 150 mA			9	52	
		V _{DS} = 1.5 V, I _D = 40 mA			10		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 200 mA		0.5		S	
Diode Forward Voltage ^a	V _{SD}	I _S = 150 mA, V _{GS} = 0 V			1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			750			
Gate-Source Charge	Q _{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 150 \text{ mA}$		75		рС	
Gate-Drain Charge	Q _{gd}			225			
Turn-On Delay Time	t _{d(on)}				50		
Rise Time	t _r	V_{DD} = 10 V, R_L = 47 Ω			25	ns -	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong\text{200}$ mA, V_GEN = 4.5 V, R_g = 10 Ω			50		
Fall Time	t _f				25		

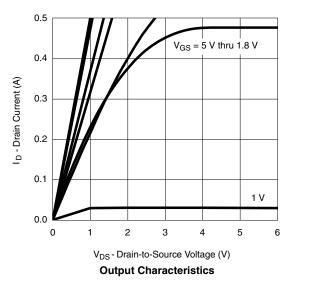
Notes:

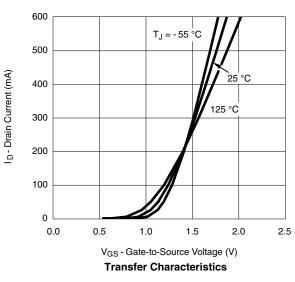
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

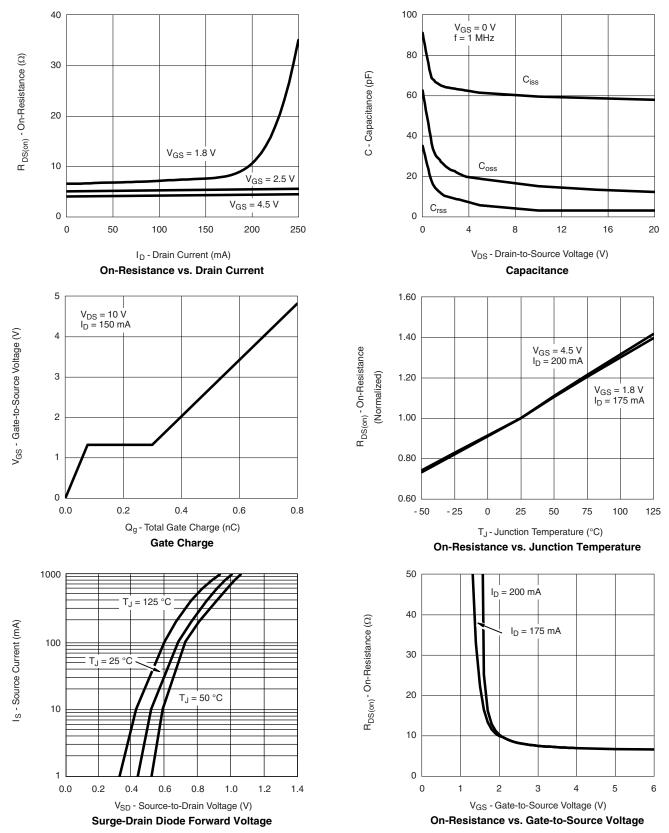
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)





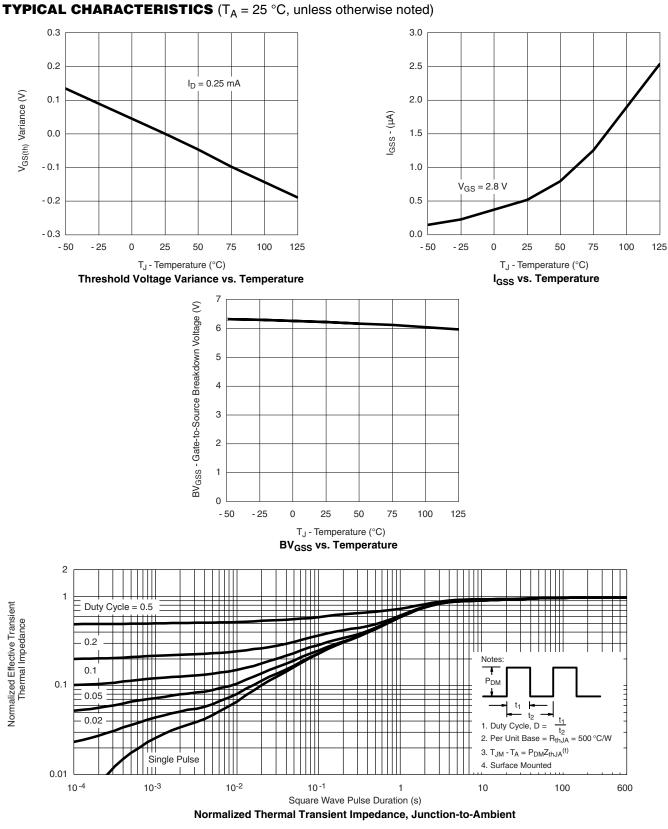


TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Si1034X

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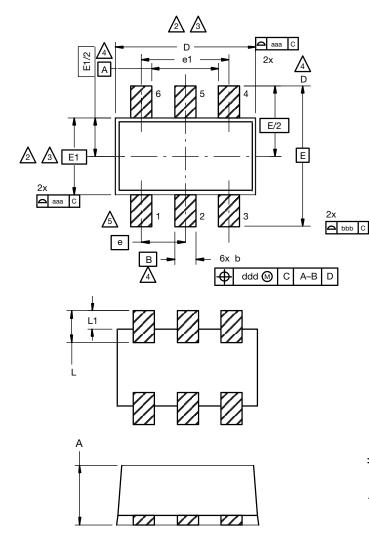
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71427.





Vishay Siliconix

SC-89 6-Leads (SOT-563F)



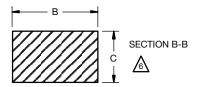
Notes

- 1. Dimensions in millimeters.
- Dimension D does not include mold flash, protrusions or gate burrs. Mold flush, protrusions or gate burrs shall not exceed 0.15 mm per dimension E1 does not include interlead flash or protrusion, interlead flash or protrusion shall not exceed 0.15 mm per side.
- Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, the bar burrs, gate burrs and interlead flash, but including any mismatch between the top and the bottom of the plastic body.

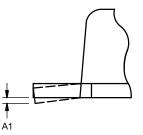
A Datums A, B and D to be determined 0.10 mm from the lead tip.

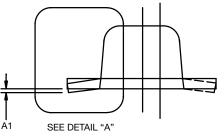
A Terminal numbers are shown for reference only.

These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.









DIM.	MILLIMETERS			
	MIN.	NOM.	MAX.	
А	0.56	0.58	0.60	
A1	0	0.02	0.10	
b	0.15	0.22	0.30	
С	0.10	0.14	0.18	
D	1.50	1.60	1.70	
E	1.50	1.60	1.70	
E1	1.15	1.20	1.25	
е	0.45	0.50	0.55	
e1	0.95	1.00	1.05	
L	0.25	0.35	0.50	
L1	0.10	0.20	0.30	
C14-0439-Rev DWG: 5880	v. C, 11-Aug-14			

Revision: 11-Aug-14

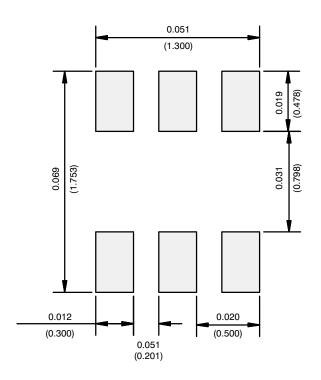
1 For technical questions, contact: <u>analogswitchtechsupport@vishay.com</u> Document Number: 71612



Application Note 826

Vishay Siliconix

RECOMMENDED MINIMUM PADS FOR SC-89: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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